# **Quad Exclusive OR Gate**

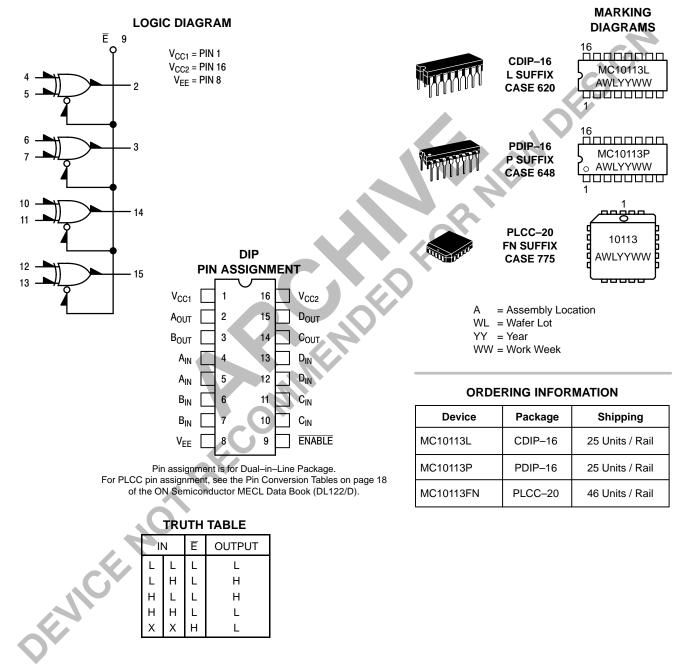
The MC10113 is a quad Exclusive OR gate, with an enable common to all four gates. The outputs may be wire–ORed together to perform a 4–bit comparison function (A = B). The enable is active low.

- $P_D = 175 \text{ mW typ/pkg}$  (No Load)
- $t_{pd} = 2.5$  ns typ
- $t_r$ ,  $t_f = 2.0$  ns typ (20%-80%)



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### **ELECTRICAL CHARACTERISTICS**

		Pin	Test Limits							
		Under		0°C		+25°C			5°C	
Characteristic	Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	Uni
Power Supply Drain Current	١ <sub>E</sub>	8		46			42		46	mAd
Input Current	I <sub>inH</sub>	4,7,10,13		425			265		265	μAd
		5,6,11,12 9		350 870			220 545		220 545	
		*	0.5	010	0.5		040	0.3	040	μAd
Output Voltage Logic 1	l <sub>inL</sub>	2	-1.060	-0.890	-0.960		-0.810	-0.890	-0.700	μAd Vdc
Output Voltage Logic 1	V <sub>OH</sub>	3	-1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	vac
		14	-1.060	-0.890	-0.960		-0.810	-0.890	-0.700	
		15	-1.060	-0.890	-0.960		-0.810	-0.890	-0.700	
Output Voltage Logic 0	V <sub>OL</sub>	2	-1.890	-1.675	-1.850		-1.650	-1.825	-1.615	Vdc
		3 14	-1.890 -1.890	-1.675 -1.675	-1.850 -1.850		-1.650 -1.650	-1.825 -1.825	-1.615 -1.615	<b>7</b>
		15	-1.890	-1.675	-1.850		-1.650	-1.825	-1.615	
Threshold Voltage Logic 1	V <sub>OHA</sub>	2	-1.080		-0.980			-0.910		Vdc
		3	-1.080		-0.980			-0.910 -0.910		
		14 15	-1.080 -1.080		-0.980 -0.980			-0.910 -0.910		
Threshold Voltage Logic 0	V <sub>OLA</sub>	2		-1.655			-1.630		-1.595	Vdd
Legio o	FOLA	3		-1.655			-1.630	~	-1.595	
		14		-1.655			-1.630 -1.630		-1.595	
Switching Times (EQC) Load		15		-1.655	Min	Tur			-1.595	
Switching Times (50Ω Load)				17	Min	Тур	Max	4.0	5.0	ns
Propagation Delay	t <sub>4+2+</sub> t <sub>4-2-</sub>	2 2	1.1 1.1	4.7 4.7	1.3 1.3	2.6 2.6	4.5 4.5	1.3 1.3	5.0 5.0	
	t <sub>9+2-</sub>	2	1.3	5.2	1.5	3.4	5.0	1.5	5.5	
	t <sub>9-2+</sub>	2	1.3	5.2	1.5	3.4	5.0	1.5	5.5	
Rise Time (20 to 80%)	t <sub>2+</sub>	2	1.1	4.2	1.1	2.5	3.9	1.1	4.4	
Fall Time (20 to 80%)	t <sub>2-</sub>	2	1.1	4.2	1.1	2.5	3.9	1.1	4.4	
Individually test each input a										

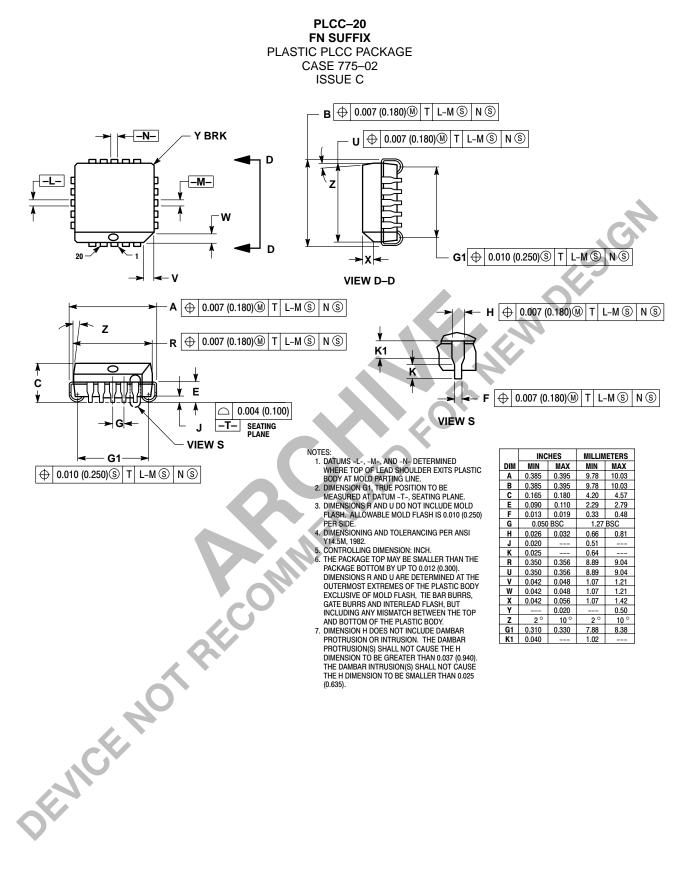
#### ELECTRICAL CHARACTERISTICS (continued)

		TEST VOLTAGE VALUES (Volts)							
		@ Test Te	mperature	V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>EE</sub>	
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
Characteristic			Pin Under Test	TEST VOLTAGE APPLIED TO PINS LISTED BELOW					
		Symbol		V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>EE</sub>	(V <sub>CC</sub> ) Gnd
Power Supply Drain (	Current	Ι <sub>Ε</sub>	8					8	1, 16
Input Current		l <sub>inH</sub>	4,7,10,13 5,6,11,12 9	* * 9				8 8 8	1, 16 1, 16 1, 16
		I <sub>inL</sub>	*		*			8	1, 16
Output Voltage	Logic 1	V <sub>OH</sub>	2 3 14 15	4 7 11 13				8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Output Voltage	Logic 0	V <sub>OL</sub>	2 3 14 15		4 7 11 13		N	8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Threshold Voltage	Logic 1	V <sub>OHA</sub>	2 3 14 15			4 6 10 12	A	8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Threshold Voltage	Logic 0	V <sub>OLA</sub>	2 3 14 15	X		<sup>C</sup>	5 7 11 13	8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Switching Times	(50 $\Omega$ Load)			+1.11V		Pulse In	Pulse Out	–3.2 V	+2.0 V
Propagation Delay		t <sub>4+2+</sub> t <sub>4-2-</sub> t <sub>9+2-</sub> t <sub>9-2+</sub>	2 2 2 2 2	4		4 4 9 9	2 2 2 2	8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	t <sub>2+</sub>	2			4	2	8	1, 16
Fall Time	(20 to 80%)	t2-	2			4	2	8	1, 16

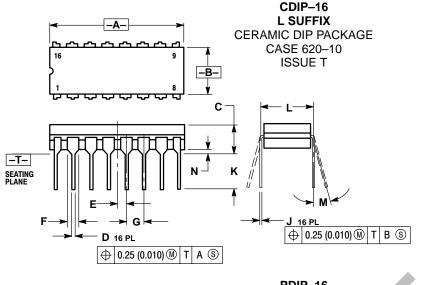
\* Individually test each input applying  $V_{IH}$  or  $V_{IL}$  to input under test.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to -2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

#### PACKAGE DIMENSIONS



### PACKAGE DIMENSIONS



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.
DIMENSION L TO CENTER OF LEAD WHEN FOOMED DRAWLES

DIMENSION LTO CENTER OF LEAD WHEN FORMED PARALLEL.
DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Е	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100 BSC		2.54 BSC		
Н	0.008	0.015	0.21	0.38	
Κ	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62 BSC		
М	0 °	15 °	0 °	15°	
Ν	0.020	0.040	0.51	1.01	

-A-<u>ሳ ስ ስ ስ</u> 16 в 0 L  $\Box \Box$ ι, հ - C S -T- SEATING PLANE H G **D** 16 PL

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE R

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS			
DIN	I MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	0.100 BSC		2.54 BSC		
н	0.050	0.050 BSC		1.27 BSC		
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
Μ	0°	10 °	0 °	10 °		
S	0.020	0.040	0.51	1.01		

## **Notes**

## **Notes**

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